

## DS90LV804

### 4-Channel 800 Mbps LVDS Buffer/Repeater

#### General Description

The DS90LV804 is a four channel 800 Mbps LVDS buffer/repeater. In many large systems, signals are distributed across cables and signal integrity is highly dependent on the data rate, cable type, length, and the termination scheme. In order to maximize signal integrity, the DS90LV804 features both an internal input and output (source) termination to eliminate these extra components from the board, and to also place the terminations as close as possible to receiver inputs and driver output. This is especially significant when driving longer cables.

The DS90LV804, available in the LLP (Leadless Leadframe Package) package, minimizes the footprint, and improves system performance.

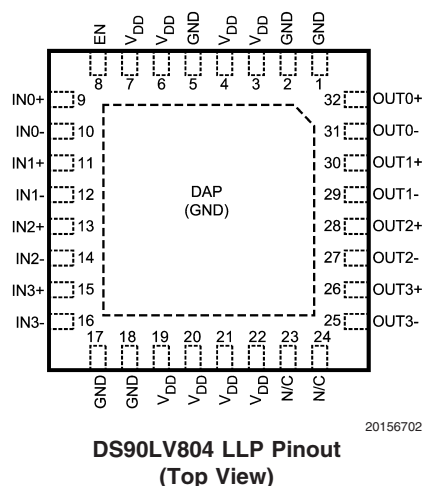
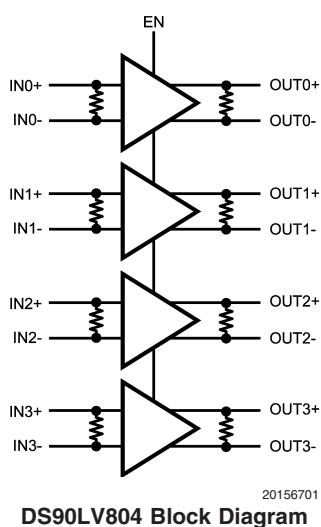
An output enable pin is provided, which allows the user to place the LVDS outputs and internal biasing generators in a TRI-STATE, low power mode.

The differential inputs interface to LVDS, and Bus LVDS signals such as those on National's 10-, 16-, and 18-bit Bus LVDS SerDes, as well as CML and LVPECL. The differential inputs are internally terminated with a 100Ω resistor to improve performance and minimize board space. This function is especially useful for boosting signals over lossy cables or point-to-point backplane configurations.

#### Features

- 800 Mbps data rate per channel
- Low output skew and jitter
- Hot plug protection
- LVDS/CML/LVPECL compatible input, LVDS output
- On-chip 100Ω input and output termination
- 15 kV ESD protection on LVDS Inputs and Outputs
- Single 3.3V supply
- Very low power consumption
- Industrial -40 to +85°C temperature range
- Small LLP Package Footprint

#### Block and Connection Diagrams



## Pin Descriptions

Pin Name	LLP Pin Number	I/O, Type	Description
DIFFERENTIAL INPUTS			
IN0+	9	I, LVDS	Channel 0 inverting and non-inverting differential inputs.
IN0–	10		
IN1+	11	I, LVDS	Channel 1 inverting and non-inverting differential inputs.
IN1–	12		
IN2+	13	I, LVDS	Channel 2 inverting and non-inverting differential inputs.
IN2–	14		
IN3+	15	I, LVDS	Channel 3 inverting and non-inverting differential inputs.
IN3–	16		
DIFFERENTIAL OUTPUTS			
OUT0+	32	O, LVDS	Channel 0 inverting and non-inverting differential outputs. (Note 2)
OUT0–	31		
OUT1+	30	O, LVDS	Channel 1 inverting and non-inverting differential outputs. (Note 2)
OUT1–	29		
OUT2+	28	O, LVDS	Channel 2 inverting and non-inverting differential outputs. (Note 2)
OUT2–	27		
OUT3+	26	O, LVDS	Channel 3 inverting and non-inverting differential outputs. (Note 2)
OUT3-	25		
DIGITAL CONTROL INTERFACE			
EN	8	I, LVTTTL	Enable pin. When EN is LOW, the driver is disabled and the LVDS outputs are in TRI-STATE. When EN is HIGH, the driver is enabled. LVCMOS/LVTTTL level input.
POWER			
V <sub>DD</sub>	3, 4, 6, 7, 19, 20, 21, 22	I, Power	V <sub>DD</sub> = 3.3V, ±5%
GND	1, 2, 5, 17, 18 (Note 1)	I, Power	Ground reference for LVDS and CMOS circuitry. For the LLP package, the DAP is used as the primary GND connection to the device. The DAP is the exposed metal contact at the bottom of the LLP-32 package. It should be connected to the ground plane with at least 4 vias for optimal AC and thermal performance. The pin numbers listed should also be tied to ground for proper biasing.
N/C	23, 24		No Connect

**Note 1:** Note that for the LLP package the GND is connected thru the DAP on the back side of the LLP package in addition to grounding actual pins on the package as listed.

**Note 2:** The LVDS outputs do not support a multidrop (BLVDS) environment. The LVDS output characteristics of the DS90LV804 device have been optimized for point-to-point backplane and cable applications.

**Absolute Maximum Ratings** (Note 3)

Charged Device Model

1000V

Supply Voltage ( $V_{DD}$ )	−0.3V to +4.0V
CMOS Input Voltage (EN)	−0.3V to ( $V_{DD}+0.3V$ )
LVDS Receiver Input Voltage	−0.3V to ( $V_{DD}+0.3V$ )
LVDS Driver Output Voltage	−0.3V to ( $V_{DD}+0.3V$ )
LVDS Output Short Circuit Current	+90 mA
Junction Temperature	+150°C
Storage Temperature	−65°C to +150°C
Lead Temperature (Solder, 4sec)	260°C
Max Pkg Power Capacity @ 25°C	4.16W
Thermal Resistance ( $\theta_{JA}$ )	30°C/W
Package Derating above +25°C	33.3mW/°C
ESD Last Passing Voltage	
HBM, 1.5k $\Omega$ , 100pF	15 kV
EIAJ, 0 $\Omega$ , 200pF	250V

**Recommended Operating Conditions**

Supply Voltage ( $V_{CC}$ )	3.15V to 3.45V
Input Voltage ( $V_I$ ) (Note 4)	0V to $V_{DD}$
Output Voltage ( $V_O$ )	0V to $V_{DD}$
Operating Temperature ( $T_A$ )	
Industrial	−40°C to +85°C

**Note 3:** Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of products outside of recommended operation conditions.

**Note 4:**  $V_{ID}$  max < 2.4V

**Electrical Characteristics**

Over recommended operating supply and temperature ranges unless other specified.

Symbol	Parameter	Conditions	Min	Typ (Note 5)	Max	Units
<b>LVTTTL DC SPECIFICATIONS (EN)</b>						
$V_{IH}$	High Level Input Voltage		2.0		$V_{DD}$	V
$V_{IL}$	Low Level Input Voltage		GND		0.8	V
$I_{IH}$	High Level Input Current	$V_{IN} = V_{DD} = V_{DDMAX}$	−10		+10	$\mu A$
$I_{IL}$	Low Level Input Current	$V_{IN} = V_{SS}$ , $V_{DD} = V_{DDMAX}$	−10		+10	$\mu A$
$C_{IN1}$	Input Capacitance	Any Digital Input Pin to $V_{SS}$		3.5		pF
$V_{CL}$	Input Clamp Voltage	$I_{CL} = -18$ mA	−1.5	−0.8		V
<b>LVDS INPUT DC SPECIFICATIONS (INn±)</b>						
$V_{TH}$	Differential Input High Threshold (Note 6)	$V_{CM} = 0.8V$ to 3.4V, $V_{DD} = 3.45V$		0	100	mV
$V_{TL}$	Differential Input Low Threshold (Note 6)	$V_{CM} = 0.8V$ to 3.4V, $V_{DD} = 3.45V$	−100	0		mV
$V_{ID}$	Differential Input Voltage	$V_{CM} = 0.8V$ to 3.4V, $V_{DD} = 3.45V$	100		2400	mV
$V_{CMR}$	Common Mode Voltage Range	$V_{ID} = 150$ mV, $V_{DD} = 3.45V$	0.05		3.40	V
$C_{IN2}$	Input Capacitance	IN+ or IN− to $V_{SS}$		3.5		pF
$I_{IN}$	Input Current	$V_{IN} = 3.45V$ , $V_{DD} = V_{DDMAX}$	−10		+10	$\mu A$
		$V_{IN} = 0V$ , $V_{DD} = V_{DDMAX}$	−10		+10	$\mu A$

## Electrical Characteristics (Continued)

Over recommended operating supply and temperature ranges unless other specified.

Symbol	Parameter	Conditions	Min	Typ (Note 5)	Max	Units
<b>LVDS OUTPUT DC SPECIFICATIONS (OUTn±)</b>						
$V_{OD}$	Differential Output Voltage (Note 6)	$R_L = 100\Omega$ external resistor between OUT+ and OUT–	250	500	600	mV
$\Delta V_{OD}$	Change in $V_{OD}$ between Complementary States		–35		35	mV
$V_{OS}$	Offset Voltage (Note 7)		1.05	1.18	1.475	V
$\Delta V_{OS}$	Change in $V_{OS}$ between Complementary States		–35		35	mV
$I_{OS}$	Output Short Circuit Current	OUT+ or OUT– Short to GND		–60	–90	mA
$C_{OUT2}$	Output Capacitance	OUT+ or OUT– to GND when TRI-STATE		5.5		pF
<b>SUPPLY CURRENT (Static)</b>						
$I_{CC}$	Total Supply Current	All inputs and outputs enabled and active, terminated with external differential load of $100\Omega$ between OUT+ and OUT–.		117	140	mA
$I_{CCZ}$	TRI-STATE Supply Current	EN = 0V		2.7	6	mA
<b>SWITCHING CHARACTERISTICS—LVDS OUTPUTS</b>						
$t_{LHT}$	Differential Low to High Transition Time	Use an alternating 1 and 0 pattern at 200 Mbps, measure between 20% and 80% of $V_{OD}$ .		210	300	ps
$t_{HLT}$	Differential High to Low Transition Time			210	300	ps
$t_{PLHD}$	Differential Low to High Propagation Delay	Use an alternating 1 and 0 pattern at 200 Mbps, measure at 50% $V_{OD}$ between input to output.		2.0	3.2	ns
$t_{PHLD}$	Differential High to Low Propagation Delay			2.0	3.2	ns
$t_{SKD1}$	Pulse Skew	$ t_{PLHD} - t_{PHLD} $		25	80	ps
$t_{SKCC}$	Output Channel to Channel Skew	Difference in propagation delay ( $t_{PLHD}$ or $t_{PHLD}$ ) among all output channels.		50	125	ps
$t_{JIT}$	Jitter (Note 8)	RJ - Alternating 1 and 0 at 400 MHz (Note 9)		1.1	1.5	psrms
		DJ - K28.5 Pattern, 800 Mbps (Note 10)		15	35	psp-p
		TJ - PRBS $2^{23}-1$ Pattern, 800 Mbps (Note 11)		30	55	psp-p
$t_{ON}$	LVDS Output Enable Time	Time from EN to OUT± change from TRI-STATE to active.			300	ns
$t_{OFF}$	LVDS Output Disable Time	Time from EN to OUT± change from active to TRI-STATE.			12	ns

**Note 5:** Typical parameters are measured at  $V_{DD} = 3.3V$ ,  $T_A = 25^\circ C$ . They are for reference purposes, and are not production-tested.

**Note 6:** Differential output voltage  $V_{OD}$  is defined as  $ABS(OUT+ - OUT-)$ . Differential input voltage  $V_{ID}$  is defined as  $ABS(IN+ - IN-)$ .

**Note 7:** Output offset voltage  $V_{OS}$  is defined as the average of the LVDS single-ended output voltages at logic high and logic low states.

**Note 8:** Jitter is not production tested, but guaranteed through characterization on a sample basis.

**Note 9:** Random Jitter, or RJ, is measured RMS with a histogram including 1500 histogram window hits. The input voltage =  $V_{ID} = 500mV$ , 50% duty cycle at 400 MHz,  $t_r = t_f = 50ps$  (20% to 80%).

**Note 10:** Deterministic Jitter, or DJ, is measured to a histogram mean with a sample size of 350 hits. The input voltage =  $V_{ID} = 500mV$ , K28.5 pattern at 800 Mbps,  $t_r = t_f = 50ps$  (20% to 80%). The K28.5 pattern is repeating bit streams of (0011111010 1100000101).

**Note 11:** Total Jitter, or TJ, is measured peak to peak with a histogram including 3500 window hits. Stimulus and fixture Jitter has been subtracted. The input voltage =  $V_{ID} = 500mV$ ,  $2^{23}-1$  PRBS pattern at 800 Mbps,  $t_r = t_f = 50ps$  (20% to 80%).

## Feature Descriptions

### INTERNAL TERMINATIONS

The DS90LV804 has integrated termination resistors on both the input and outputs. The inputs have a  $100\Omega$  resistor across the differential pair, placing the receiver termination as close as possible to the input stage of the device. The LVDS outputs also contain an integrated  $100\Omega$  ohm termination resistor, this resistor is used to reduce the effects of Near End Crosstalk (NEXT) and does not take the place of the  $100\Omega$  ohm termination at the inputs to the receiving device. The integrated terminations improve signal integrity and decrease the external component count resulting in space savings.

### OUTPUT CHARACTERISTICS

The output characteristics of the DS90LV804 have been optimized for point-to-point backplane and cable applications, and are not intended for multipoint or multidrop signaling.

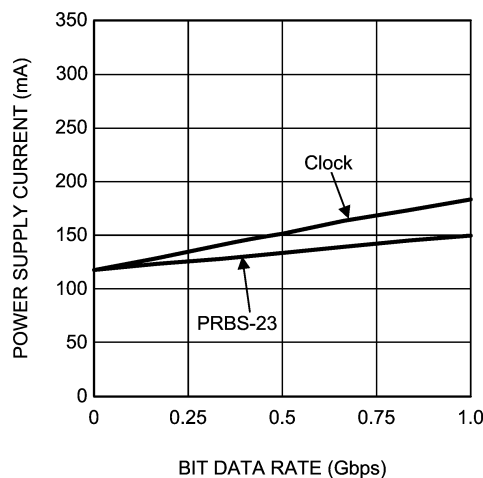
### TRI-STATE MODE

The EN input activates a hardware TRI-STATE mode. When the TRI-STATE mode is active (EN=L), all input and output buffers and internal bias circuitry are powered off and disabled. Outputs are tri-stated in TRI-STATE mode. When exiting TRI-STATE mode, there is a delay associated with turning on bandgap references and input/output buffer circuits as indicated in the LVDS Output Switching Characteristics.

### INPUT FAILSAFE BIASING

External pull up and pull down resistors may be used to provide enough of an offset to enable an input failsafe under open-circuit conditions. This configuration ties the positive LVDS input pin to  $V_{DD}$  thru a pull up resistor and the negative LVDS input pin is tied to GND by a pull down resistor. The pull up and pull down resistors should be in the  $5k\Omega$  to  $15k\Omega$  range to minimize loading and waveform distortion to the driver. The common-mode bias point ideally should be set to approximately 1.2V (less than 1.75V) to be compatible with the internal circuitry. Please refer to application note AN-1194 "Failsafe Biasing of LVDS Interfaces" for more information.

## TYPICAL PERFORMANCE CHARACTERISTICS



20156741

Dynamic power supply current was measured while running a clock or PRBS  $2^{23}-1$  pattern with all 4 channels active.  $V_{CC} = 3.3V$ ,  $T_A = +25^\circ C$ ,  $V_{ID} = 0.5V$ ,  $V_{CM} = 1.2V$

Power Supply Current vs. Bit Data Rate

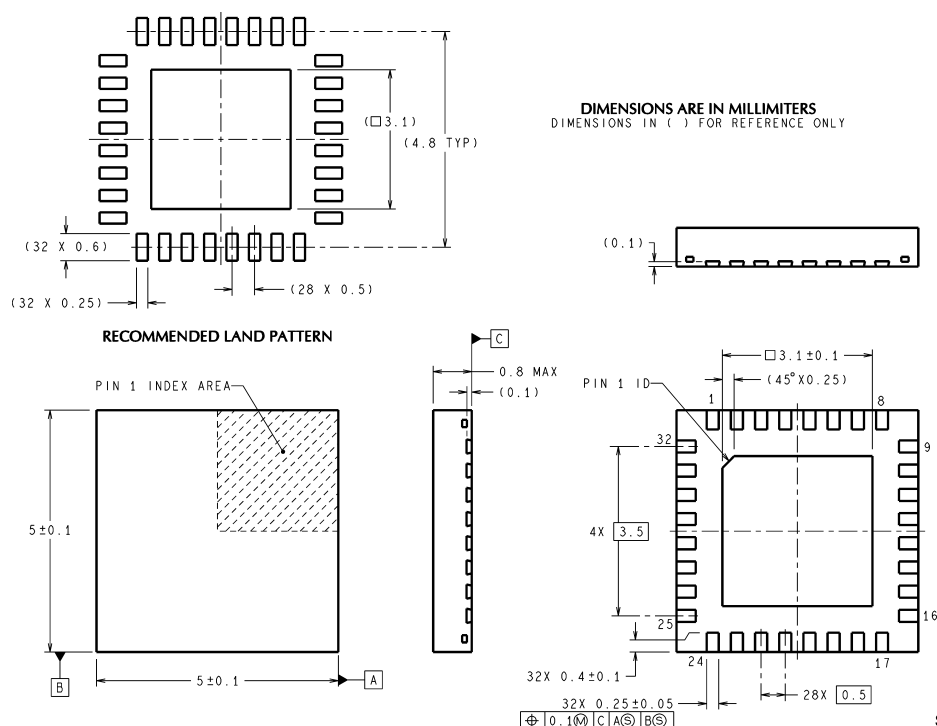
## Packaging Information

The Leadless Leadframe Package (LLP) is a leadframe based chip scale package (CSP) that may enhance chip speed, reduce thermal impedance, and reduce the printed circuit board area required for mounting. The small size and very low profile make this package ideal for high density PCBs used in small-scale electronic applications such as cellular phones, pagers, and handheld PDAs. The LLP package is offered in the no Pullback configuration. In the no Pullback configuration the standard solder pads extend and terminate at the edge of the package. This feature offers a visible solder fillet after board mounting.

The LLP has the following advantages:

- Low thermal resistance
- Reduced electrical parasitics
- Improved board space efficiency
- Reduced package height
- Reduced package mass

For more details about LLP packaging technology, refer to applications note AN-1187, "Leadless Leadframe Package"



National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.

For the most current product information visit us at [www.national.com](http://www.national.com).

## LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## BANNED SUBSTANCE COMPLIANCE

National Semiconductor manufactures products and uses packing materials that meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.

Leadfree products are RoHS compliant.



**National Semiconductor  
Americas Customer  
Support Center**  
Email: [new.feedback@nsc.com](mailto:new.feedback@nsc.com)  
Tel: 1-800-272-9959

www.national.com

**National Semiconductor**  
**Europe Customer Support Center**  
 Fax: +49 (0) 180-530 85 86  
 Email: [europe.support@nsc.com](mailto:europe.support@nsc.com)  
 Deutsch Tel: +49 (0) 69 9508 6208  
 English Tel: +44 (0) 870 24 0 2171  
 Français Tel: +33 (0) 1 41 91 8790

**National Semiconductor**  
**Asia Pacific Customer**  
**Support Center**  
Email: [ap.support@nsc.com](mailto:ap.support@nsc.com)

**National Semiconductor**  
**Japan Customer Support Center**  
 Fax: 81-3-5639-7507  
 Email: [jpn.feedback@nsc.com](mailto:jpn.feedback@nsc.com)  
 Tel: 81-3-5639-7560